

## Standard Rectifier Module

|                         |          |
|-------------------------|----------|
| <b>3~<br/>Rectifier</b> |          |
| $V_{RRM}$               | = 1200 V |
| $I_{DAV}$               | = 90 A   |
| $I_{FSM}$               | = 750 A  |

### 3~ Rectifier Bridge

Part number

VUO82-12N07



 E72873



#### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

#### Applications:

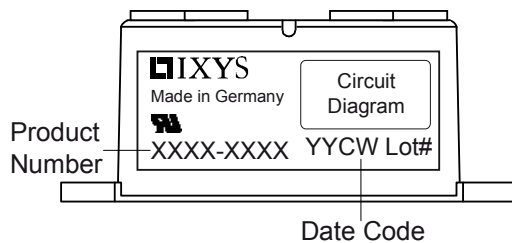
- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

#### Package: PWS-D

- Industry standard outline
- RoHS compliant
- Easy to mount with two screws
- Base plate: Copper internally DCB isolated
- Advanced power cycling

| Rectifier  |  |  |                              | Ratings                     |      |      |                   |                             |
|------------|--|--|------------------------------|-----------------------------|------|------|-------------------|-----------------------------|
| Symbol     | Definition                                   | Conditions                               |                              | min.                        | typ. | max. | Unit              |                             |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage |  |                              |                             |      | 1300 | V                 |                             |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     |  |                              |                             |      | 1200 | V                 |                             |
| $I_R$      | reverse current                              | $V_R = 1200$ V                           | $T_{VJ} = 25^\circ\text{C}$  |                             |      | 100  | $\mu\text{A}$     |                             |
|            |  | $V_R = 1200$ V                           | $T_{VJ} = 150^\circ\text{C}$ |                             |      | 1.5  | mA                |                             |
| $V_F$      | forward voltage drop                         | $I_F = 30$ A                             | $T_{VJ} = 25^\circ\text{C}$  |                             |      | 1.08 | V                 |                             |
|            |  |  |                              |                             |      | 1.35 | V                 |                             |
|            |  | $I_F = 90$ A                             | $T_{VJ} = 125^\circ\text{C}$ |                             |      | 0.99 | V                 |                             |
|            |  |  |                              |                             |      | 1.33 | V                 |                             |
| $I_{DAV}$  | bridge output current                        | $T_C = 115^\circ\text{C}$<br>rectangular | $T_{VJ} = 150^\circ\text{C}$ |                             |      | 90   | A                 |                             |
|            |  |  |                              |                             |      |      |                   | $d = \frac{1}{3}$           |
| $V_{FO}$   | threshold voltage                            |  |                              |                             |      | 0.78 | V                 |                             |
| $r_F$      | slope resistance                             |  |                              |                             |      | 6    | m $\Omega$        |                             |
| $R_{thJC}$ | thermal resistance junction to case          |  |                              |                             |      | 0.9  | K/W               |                             |
| $R_{thCH}$ | thermal resistance case to heatsink          |  |                              |                             | 0.4  |      | K/W               |                             |
| $P_{tot}$  | total power dissipation                      |  |                              | $T_C = 25^\circ\text{C}$    |      | 135  | W                 |                             |
| $I_{FSM}$  | max. forward surge current                   | $t = 10$ ms; (50 Hz), sine               | $T_{VJ} = 45^\circ\text{C}$  |                             |      | 750  | A                 |                             |
|            |  |  |                              |                             |      |      |                   | $t = 8,3$ ms; (60 Hz), sine |
|            |  | $t = 10$ ms; (50 Hz), sine               | $T_{VJ} = 150^\circ\text{C}$ |                             |      |      | 640               | A                           |
|            |  |  |                              |                             |      |      |                   |                             |
| $I^2t$     | value for fusing                             | $t = 10$ ms; (50 Hz), sine               | $T_{VJ} = 45^\circ\text{C}$  |                             |      | 2.82 | kA <sup>2</sup> s |                             |
|            |  |  |                              |                             |      |      |                   | $t = 8,3$ ms; (60 Hz), sine |
|            |  | $t = 10$ ms; (50 Hz), sine               | $T_{VJ} = 150^\circ\text{C}$ |                             |      |      | 2.05              | kA <sup>2</sup> s           |
|            |  |  |                              |                             |      |      |                   |                             |
| $C_J$      | junction capacitance                         | $V_R = 400$ V; $f = 1$ MHz               |                              | $T_{VJ} = 25^\circ\text{C}$ |      | 27   | pF                |                             |

| Package PWS-D  |  |                      | Ratings |      |      |      |
|----------------|--|----------------------|---------|------|------|------|
| Symbol         | Definition   | Conditions           | min.    | typ. | max. | Unit |
| $I_{RMS}$      | RMS current  | per terminal         |         |      | 150  | A    |
| $T_{stg}$      | storage temperature  |                      | -40     |      | 125  | °C   |
| $T_{VJ}$       | virtual junction temperature                                 |                      | -40     |      | 150  | °C   |
| <b>Weight</b>  |  |                      |         | 159  |      | g    |
| $M_D$          | mounting torque  |                      | 4.25    |      | 5.75 | Nm   |
| $M_T$          | terminal torque  |                      | 4.25    |      | 5.75 | Nm   |
| $d_{Spp/App}$  | creepage distance on surface   striking distance through air | terminal to terminal | 9.5     |      |      | mm   |
| $d_{Spb/Appb}$ |  | terminal to backside | 26.0    |      |      | mm   |
| $V_{ISOL}$     | isolation voltage  | t = 1 second         | 3000    |      |      | V    |
|                |  | t = 1 minute         | 2500    |      |      | V    |



| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-------------|--------------------|---------------|----------|----------|
| Standard | VUO82-12NO7 | VUO82-12NO7        | Box           | 10       | 460419   |

### Equivalent Circuits for Simulation

\* on die level

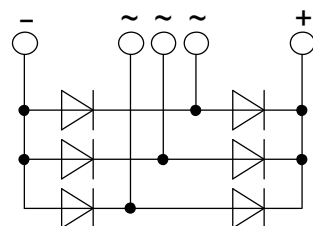
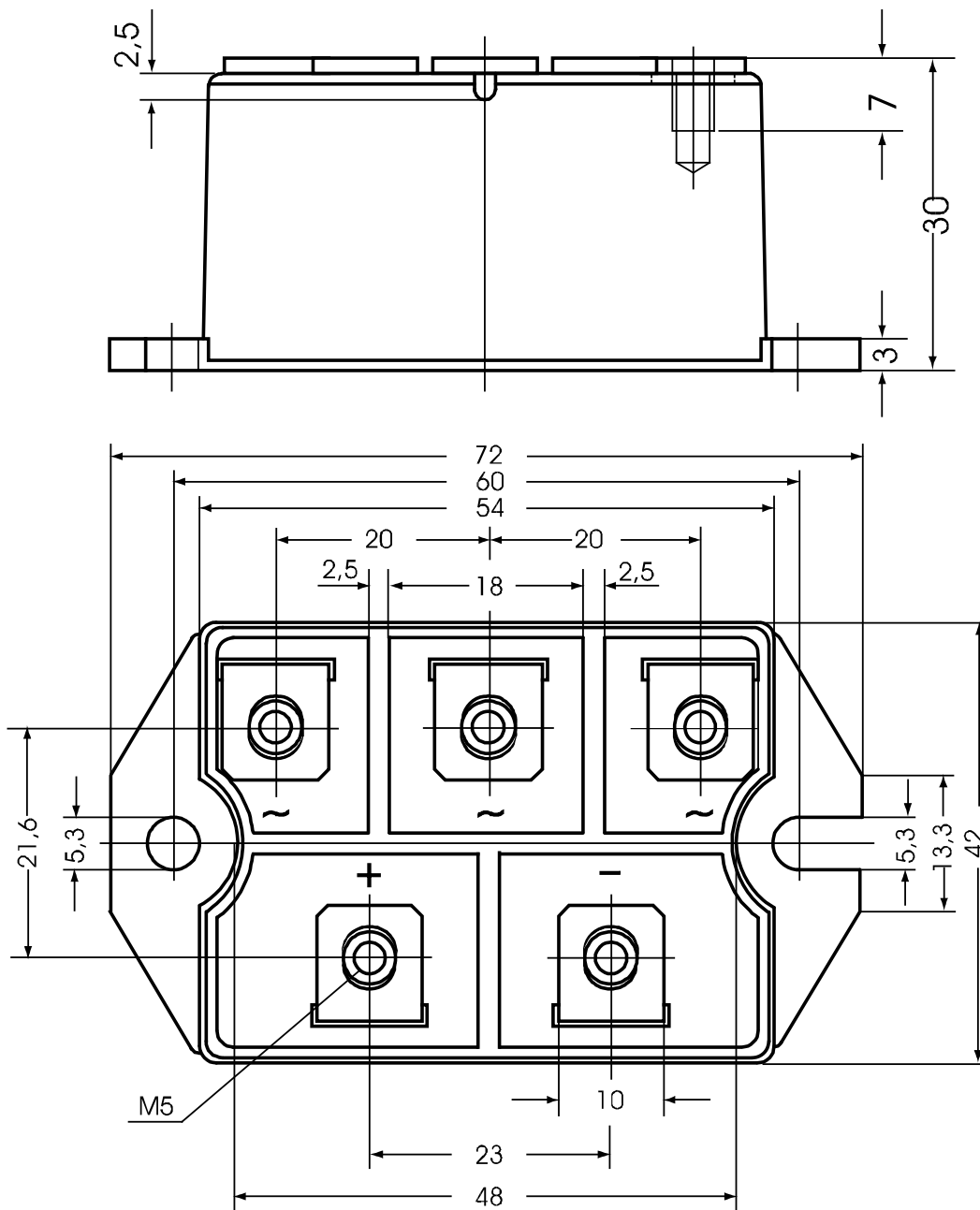
$T_{VJ} = 150\text{ °C}$



Rectifier

|              |                    |      |    |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage  | 0.78 | V  |
| $R_{0\ max}$ | slope resistance * | 4.8  | mΩ |

**Outlines PWS-D**



## Rectifier

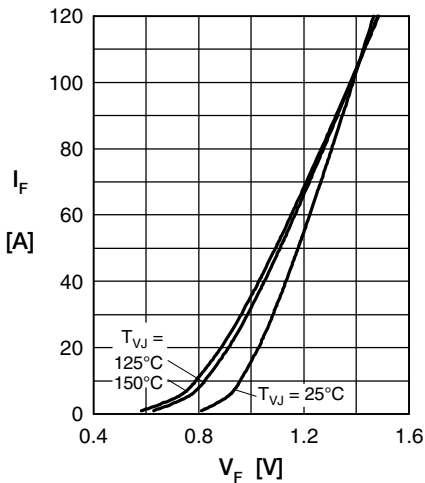


Fig. 1 Forward current versus voltage drop per diode

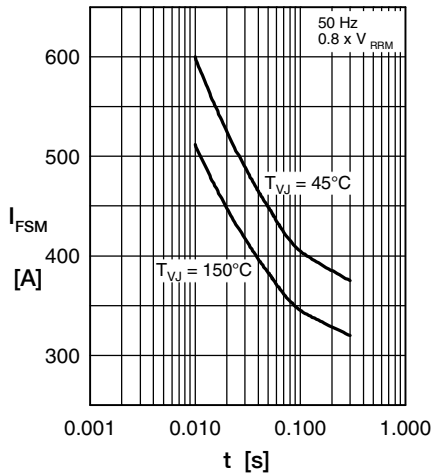


Fig. 2 Surge overload current

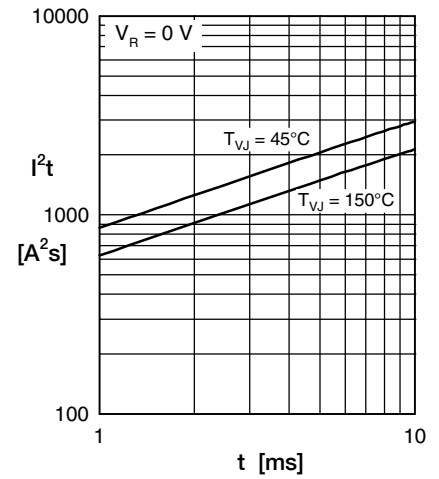


Fig. 3  $I^2t$  versus time per diode

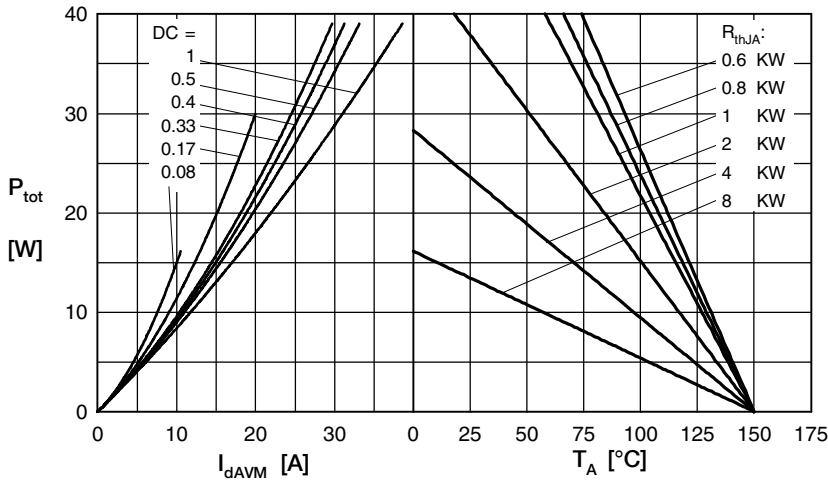


Fig. 4 Power dissipation vs. direct output current & ambient temperature

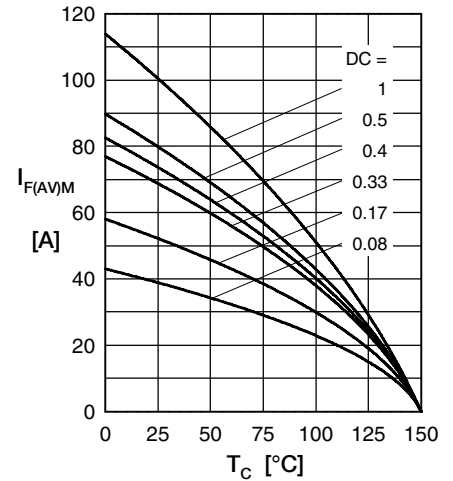


Fig. 5 Max. forward current vs. case temperature

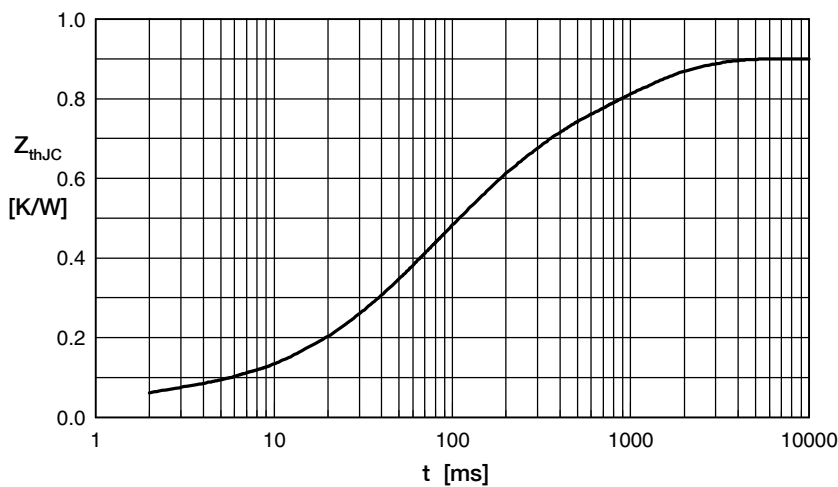


Fig. 6 Transient thermal impedance junction to case

Constants for  $Z_{thJC}$  calculation:

| i | $R_{th}$ (K/W) | $t_i$ (s) |
|---|----------------|-----------|
| 1 | 0.05           | 0.001     |
| 2 | 0.14           | 0.030     |
| 3 | 0.18           | 0.070     |
| 4 | 0.28           | 0.150     |
| 5 | 0.25           | 0.950     |

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